

Vishay General Semiconductor

# Surface Mount TRANSZORB® Transient Voltage Suppressors



DO-214AA (SMBJ)

3.3 V

600 W

60 A

175 °C

**PRIMARY CHARACTERISTICS** 

V<sub>WM</sub>

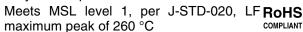
P<sub>PPM</sub>

I<sub>FSM</sub>

T<sub>.1</sub> max.

### FEATURES

- Uni-directional polarity only
- Peak pulse power: 600 W (10/1000  $\mu s)$
- Excellent clamping capability
- Very fast response time



- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

### **TYPICAL APPLICATIONS**

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units specifically for protecting 3.3 V supplied sensitive equipment against transient overvoltages.

#### **MECHANICAL DATA**

Case: DO-214AA (SMBJ)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS compliant, commercial grade Base P/NHE3 - RoHS compliant, high reliability/ automotive grade (AEC Q101 qualified)

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Peak pulse power dissipation <sup>(1)(2)</sup>	P <sub>PPM</sub>	600	W			
Peak pulse current with a 10/1000 $\mu s$ waveform (Fig. 1)	I <sub>PP</sub>	50	А			
Peak pulse current with a 8/20 waveform (Fig. 1)	I <sub>PPM</sub>	200	А			
Non repetitive peak forward surge current 8.3 ms single half sine-wave <sup>(2)</sup>	I <sub>FSM</sub>	60	А			
Power dissipation on infinite heatsink, $T_L = 75 \ ^{\circ}C$	PD	5	W			
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 65 to + 175	°C			

Notes:

(1) Non-repetitive current pulse, per Fig. 1

(2) Mounted on 0.2 x 0.2" (5.0 x 5.0 mm) copper pads to each terminal

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25$ °C unless otherwise noted)											
DEVICE TYPE	DEVICE MARKING CODE	BREAKDOWN VOLTAGE V <sub>BR</sub> AT I <sub>T</sub> MIN.		MAXIMUM REVERSE LEAKAGE CURRENT I <sub>R</sub> AT V <sub>WM</sub> MAX.		MAXIMUM CLAMPING VOLTAGE V <sub>C</sub> AT I <sub>PP</sub> 10/1000 µs		MAXIMUM CLAMPING VOLTAGE V <sub>C</sub> AT I <sub>PPM</sub> 8/20 µs		TYPICAL TEMP. COEFFICIENT OF V <sub>BR</sub>	TYPICAL JUNCTION CAPACITANCE C <sub>J</sub> AT 0 V 1 MHz
		v	mA	μA	V	V	Α	V	Α	(10 <sup>-4</sup> /°C)	pF
SMBJ3V3	KC	4.1	1.0	200	3.3	7.3	50	10.3	200	- 5.3	5200



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<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \degree C$ unless otherwise noted)							
PARAMETER	SYMBOL	VALUE	UNIT				
Typical thermal resistance, junction to lead <sup>(1)</sup>	$R_{ ext{ heta}JL}$	20	°C/W				
Typical thermal resistance, junction to ambient <sup>(2)</sup>	$R_{ ext{ heta}JA}$	100	°C/W				

Notes:

(1) Thermal resistance from junction to lead - mounted on 0.2 x 0.2" (5.0 x 5.0 mm) copper pads to each terminal

(2) Thermal resistance from junction to ambient - mounted on the recommended P.C.B. pad layout

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SMBJ3V3-E3/52	0.096	52	750	7" diameter plastic tape and reel		
SMBJ3V3-E3/5B	0.096	5B	3200	13" diameter plastic tape and reel		
SMBJ3V3HE3/52 (1)	0.096	52	750	7" diameter plastic tape and reel		
SMBJ3V3HE3/5B (1)	0.096	5B	3200	13" diameter plastic tape and reel		

Note:

(1) Automotive grade AEC Q101 qualified

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

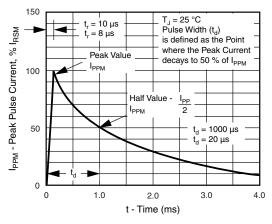


Figure 1. Pulse Waveform

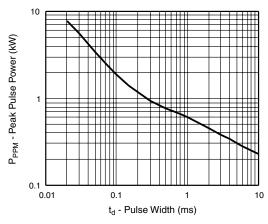


Figure 2. Peak Pulse Power Rating Curve

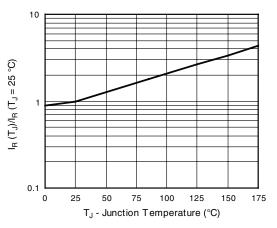
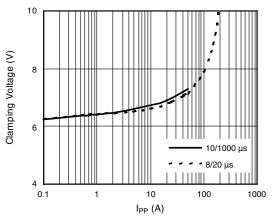
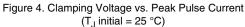


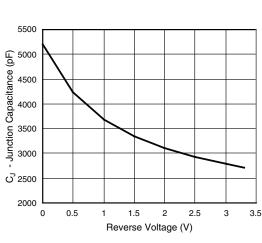
Figure 3. Relative Variation of Leakage Current vs. Junction Temperature





For technical questions within your region, please contact one of the following: <u>PDD-Americas@vishay.com</u>, <u>PDD-Asia@vishay.com</u>, <u>PDD-Europe@vishay.com</u>

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Figure 5. Typical Junction Capacitance

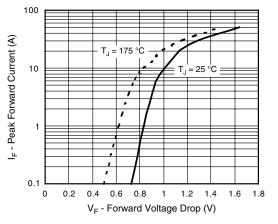


Figure 7. Typical Peak Forward Voltage Drop vs. Peak Forward Current

**Mounting Pad Layout** 

0.220 REF.

0.085 (2.159) MAX.

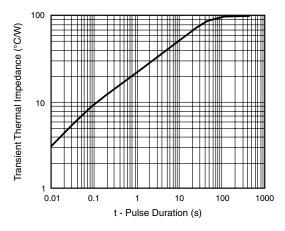
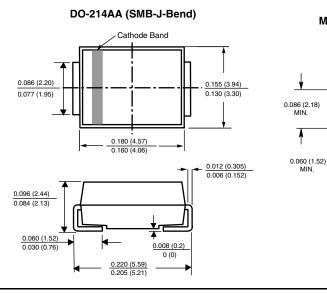


Figure 6. Typical Transient Thermal Impedance





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